

2N4400



MMBT4400



NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	6.0	V
I _C	Collector Current - Continuous	600	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units	
		2N4400	*MMBT4400		
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/∘C	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	83.3	2.0	°C/W	
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W	

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Electri	Electrical Characteristics TA = 25°C unless otherwise noted				
Symbol	Parameter	Test Conditions	Min	Мах	Units

OFF CHARACTERISTICS

V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 100 \ \mu {\rm A}, \ I_{\rm C} = 0$	6.0		V
I _{CEX}	Collector Cutoff Current	$V_{CE} = 35 \text{ V}, V_{EB} = 0.4 \text{ V}$		0.1	μΑ
I _{BL}	Emitter Cutoff Current	$V_{CE} = 35 \text{ V}, V_{EB} = 0.4 \text{ V}$		0.1	μΑ

ON CHARACTERISTICS*

h _{FE}	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	20		
		$V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$	40		
		$V_{CE} = 1.0 \text{ V}, I_{C} = 150 \text{ mA}$	50	150	
		$V_{CE} = 2.0 \text{ V}, I_{C} = 500 \text{ mA}$	20		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 150 mA, I _B =15 mA		0.40	V
()		$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		0.75	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 150 mA, I _B =15 mA	0.75	0.95	V
()		$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 50 \text{ mA}$		1.2	V

SMALL SIGNAL CHARACTERISTICS

C _{ob}	Output Capacitance	V _{CB} = 5.0 V, f = 140 kHz		6.5	pF
C _{ib}	Input Capacitance	V _{EB} = 0.5 V, f = 140 kHz		30	pF
h _{fe}	Small-Signal Current Gain	$I_{C} = 20 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 100 MHz	2.0		
h _{fe}	Small-Signal Current Gain	$V_{CE} = 10 \text{ V}, I_C = 1.0 \text{ mA},$	20	250	
h _{ie}	Input Impedance	f = 1.0 kHz	0.5	7.5	KΩ
h _{re}	Voltage Feedback Ratio		0.1	8.0	x 10 ⁻⁴
h _{oe}	Output Admittance		1.0	30	μmhos

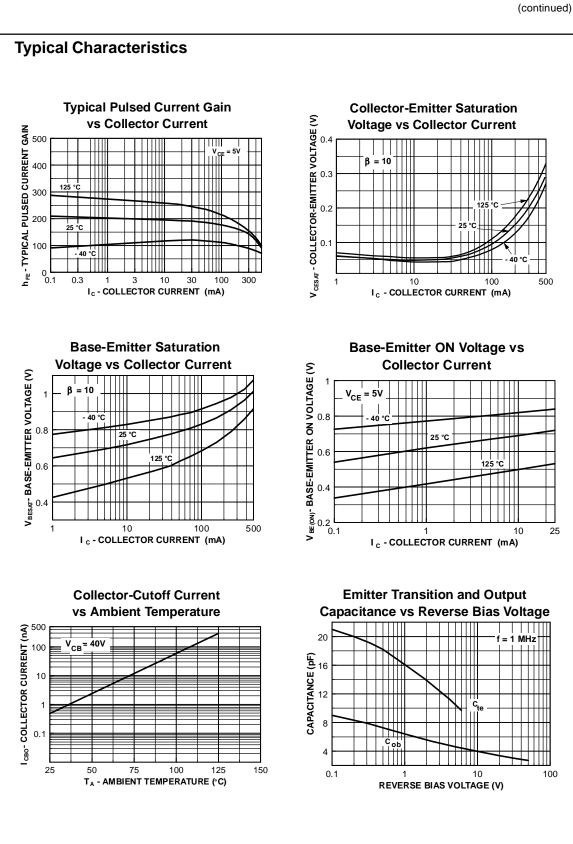
SWITCHING CHARACTERISTICS

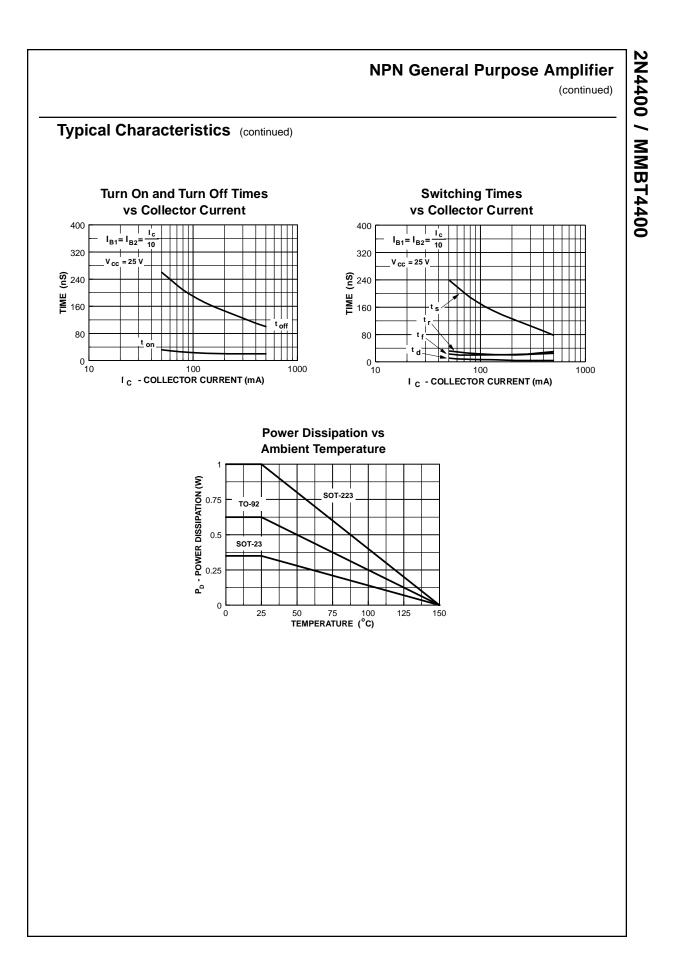
t _d	Delay Time	$V_{\rm CC} = 30 \text{ V}, \text{ I}_{\rm C} = 150 \text{ mA},$	15	ns
tr	Rise Time	I _{B1} = 15 mA ,V _{EB} = 2 V	20	ns
ts	Storage Time	$V_{CC} = 30 \text{ V}, I_{C} = 150 \text{ mA}$	225	ns
t _f	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$	30	ns

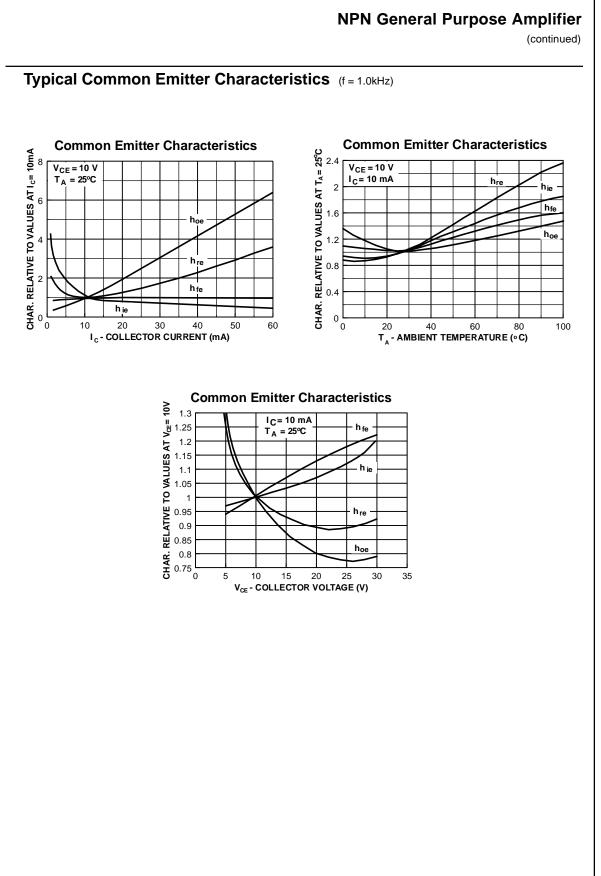
*Pulse Test: Pulse Width £ 300 ms, Duty Cycle £ 2.0%

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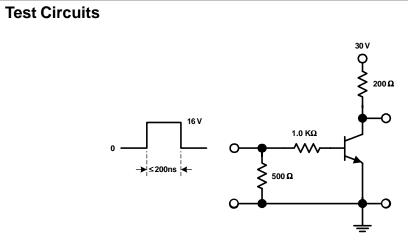


FIGURE 1: Saturated Turn-On Switching Timer

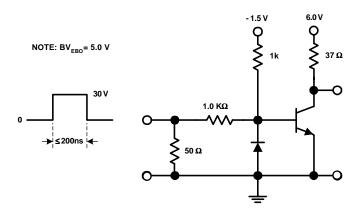


FIGURE 2: Saturated Turn-Off Switching Time

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